

FRED Module

Fast Recovery Epitaxial Diode

Common Anode

Preliminary

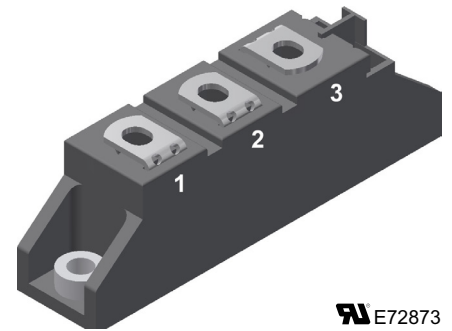
$$V_{RRM} = 600 \text{ V}$$


$$I_{FAV} = 95 \text{ A}$$

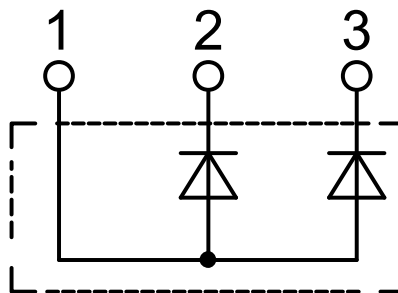
$$t_{rr} = 35 \text{ ns}$$

Part number

MPA 95-06DA



 E72873



Features / Advantages:

- Planar passivated chips
- Low switching losses
- Soft recovery behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Applications:

- Antiparallel diode for high frequency switching devices
- Free wheeling diode in converters and motor control circuits
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Package: TO-240AA

- Isolation voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

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Littelfuse/IXYS reserves the right to change limits, test conditions and dimensions.
 Data according to IEC 60747 and per semiconductor unless otherwise specified.

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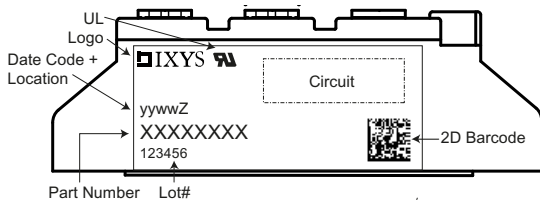


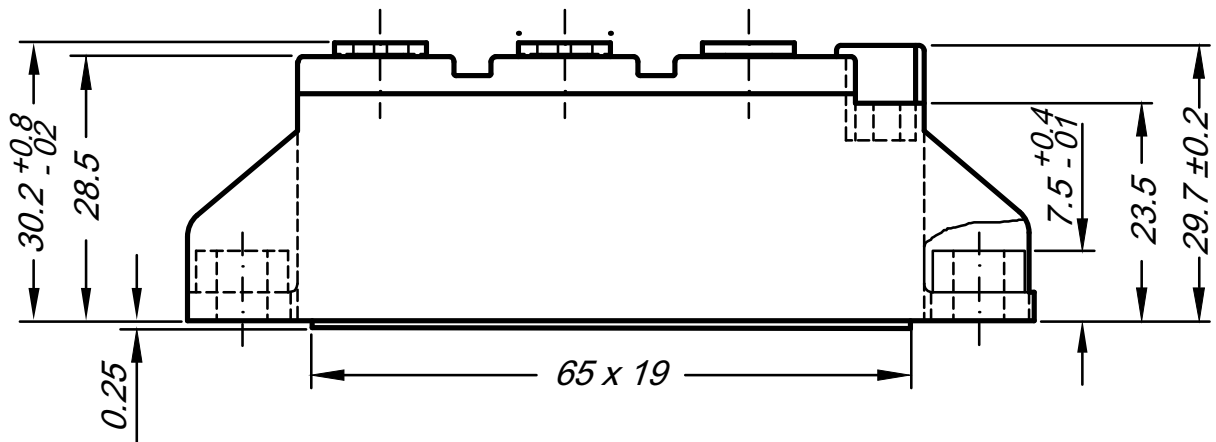
Preliminary

Diode				Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage		$T_{VJ} = 25^{\circ}\text{C}$			600	V
V_{RRM}	max. repetitive reverse blocking voltage		$T_{VJ} = 25^{\circ}\text{C}$			600	V
I_{FRMS}	RMS forward current					200	A
$I_{FAV}^{①}$	average forward current	sine 180°	$T_C = 110^{\circ}\text{C}$			95	A
I_{FSM}	max. surge forward current	$t = 10 \text{ ms}$ (50 Hz), sine	$T_{VJ} = 45^{\circ}\text{C}$			1200	A
P_{tot}			$T_C = 25^{\circ}\text{C}$			215	W
I_R	reverse current	$V_R = V_{RRM}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$			1.3 5	mA mA
V_F	forward voltage	$I_F = 50 \text{ A}$ $I_F = 100 \text{ A}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$			1.73 1.22 1.89 1.40	V V V V
V_{T0}	threshold voltage	for power-loss calculations only	$T_{VJ} = T_{VJM}$			0.98	V
r_T	slope resistance					2.3	m Ω
R_{thJC}	thermal resistance junction to case					0.575	K/W
R_{thCH}	thermal resistance junction to heatsink				0.1		K/W
t_{rr}	max. reverse recovery current	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; -di/dt = 300 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^{\circ}\text{C}$		35		ns
I_{RM}	reverse recovery time	$I_F = 130 \text{ A}; V_R = 100 \text{ V}$ $-di/dt = 300 \text{ A}/\mu\text{s}; L \leq 0.05 \mu\text{H}$	$T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 100^{\circ}\text{C}$		5.5	4.0 6.8	A A
① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$							

Preliminary

Package TO-240AA				Ratings		
Symbol	Definitions	Conditions		min.	typ.	max.
I_{RMS}	RMS current	per terminal				200 A
T_{VJ}	virtual junction temperature			-40		150 °C
T_{op}	operation temperature			-40		125 °C
T_{stg}	storage temperature			-40		125 °C
Weight					76	g
M_D	mounting torque			2.5		4 Nm
M_T	terminal torque			2.5		4 Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	13.0	9.7		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
V_{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4800		V
		t = 1 minute		4000		V





General tolerance: DIN ISO 2768 class „c“

